

Typically for any problem that has a known solution, WKB will exactly match that solution. Nevertheless, WKB should not be trusted for small n .

Eg - H atom bound state: $E < 0$, $E = -\frac{1}{2} \frac{m c^2 \alpha^2}{n^2}$ Fine structure constant $\approx \frac{1}{137}$

$n = n_r + l + 1$

Convert 3d problem to 1d via $\psi = \frac{u(r)}{r} Y_{lm}(\theta, \phi)$
 with boundary condition $u(r=0) = 0$

$$-\frac{\hbar^2}{2m} u'' + \underbrace{\frac{\hbar^2 l(l+1)}{2m r^2}}_{\text{"centrifugal" potential}} u - \underbrace{\frac{Z e^2}{4\pi\epsilon_0 r}}_{\text{attractive electrostatic potential}} u = -|E| u$$

$$-u'' = \frac{2m}{\hbar^2} \left\{ \frac{Z e^2}{4\pi\epsilon_0 r} - \frac{\hbar^2 l(l+1)}{2m r^2} - |E| \right\} u$$

$$= \frac{2m|E|}{\hbar^2 r^2} \left\{ \frac{Z e^2 r}{4\pi\epsilon_0 |E|} - \frac{\hbar^2 (l+1/2)^2}{2m|E|} - r^2 \right\} u$$

proper treatment of boundary condition $u(r=0) = 0$ results in $l(l+1) \rightarrow (l+1/2)^2$
 The difference is just $1/4$

This is quadratic $-(r-a)(r-b)$ where linear term $a+b = \frac{Z e^2}{4\pi\epsilon_0 |E|}$ & constant term $ab = \frac{\hbar^2 (l+1/2)^2}{2m|E|}$

Table: $\int_a^b \frac{1}{x} \sqrt{-(x-a)(x-b)} dx = \frac{\pi}{2} (\sqrt{b} - \sqrt{a})^2 = \frac{\pi}{2} (a+b - 2\sqrt{ab})$

Above: $-u'' = k^2 u$ where $k = \sqrt{\frac{2m|E|}{\hbar^2} \frac{1}{r} \sqrt{-(r-a)(r-b)}}$

WKB: $\pi(n_r + 1/2) = \int_a^b k(r) dr = \sqrt{\frac{2m|E|}{\hbar^2}} \int_a^b \frac{1}{r} \sqrt{-(r-a)(r-b)} dr$

$$= \frac{\sqrt{2m|E|}}{\hbar} \frac{\pi}{2} \left(\frac{Z e^2}{4\pi\epsilon_0 |E|} - 2 \sqrt{\frac{\hbar^2 (l+1/2)^2}{2m|E|}} \right)$$

$n_r + l + 1 \equiv n$

$$= \frac{\pi}{2} \left(\frac{\sqrt{2m c^2} Z e^2}{4\pi\epsilon_0 \hbar c \sqrt{|E|}} - 2(l+1/2) \right)$$

$$(n_r + 1/2 + l + 1/2) = \sqrt{\frac{m c^2}{2}} \frac{n}{\sqrt{|E|}}$$

$$\sqrt{|E|} = \sqrt{\frac{mc^2}{2} \frac{d^2}{h}}$$

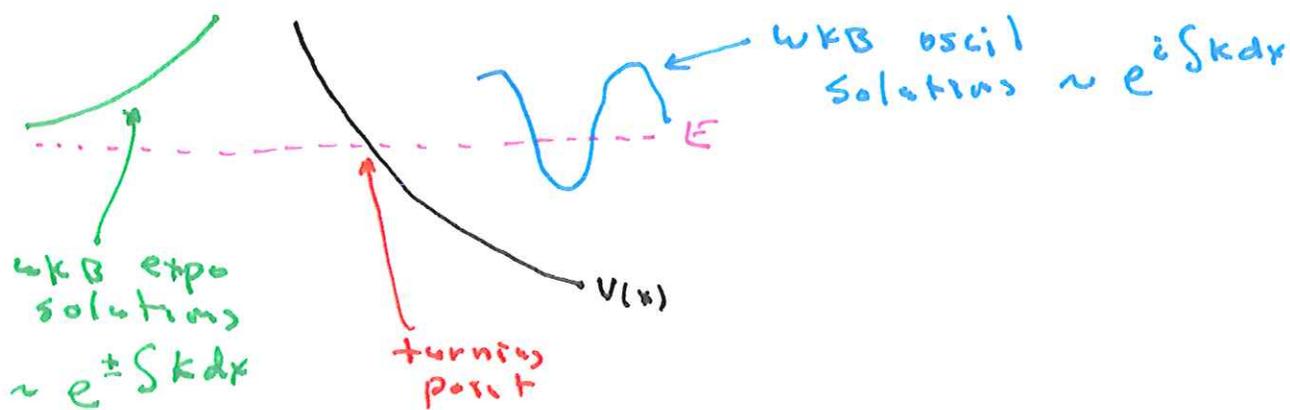
$$|E| = \frac{mc^2}{2} \frac{d^2}{h^2} \quad \checkmark$$

In general $k = \sqrt{\frac{2m(E-V)}{\hbar^2}}$ depends on E , so $\int k dx$ depends on E . WKB condition needs

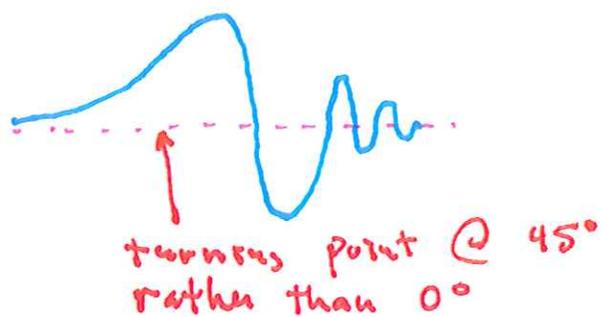
$$\text{function}(E) = \int k dx = \pi(n + \frac{1}{2})$$

Invert this result to get $E = \text{Function}(n)$

WKB is valid away from turning points where $E=V$



How connect solutions across turning point? Approx $V(x)$ as a linear function which has known solution $A_i(x)$... connect oscill part of A_i with $e^{i S k dx}$... connect expo part of A_i with $e^{S k dx}$... much calculations ... result at turning point its as if WKB solution was at 45° - half way to zero



Remark: if have "hard" $V=\infty$ turning point then $\psi=0$ there ... i.e. WKB starts at $\theta=0^\circ$

with a "hard" ($V = \infty$) boundary we need integer # of half wavelengths (just like standing waves in organ pipe) $\Rightarrow \int k dx = \pi n$

$n = 1, 2, 3$ # $\frac{\lambda}{2}$ between turning points

$2\pi \frac{dx}{\lambda} = 2\pi$ (fraction of wavelength)

seek the sum of wavelength fractions to be integer
2

If you have "linear" turning points - you start

at $45^\circ = \frac{1}{8} \lambda$ so

$$\frac{1}{2\pi} \int k dx + \frac{1}{8} \times [\text{\# linear turning pts}] = \frac{n}{2}$$

total wavelengths between turning points

0, 1, 2 both hard

both linear

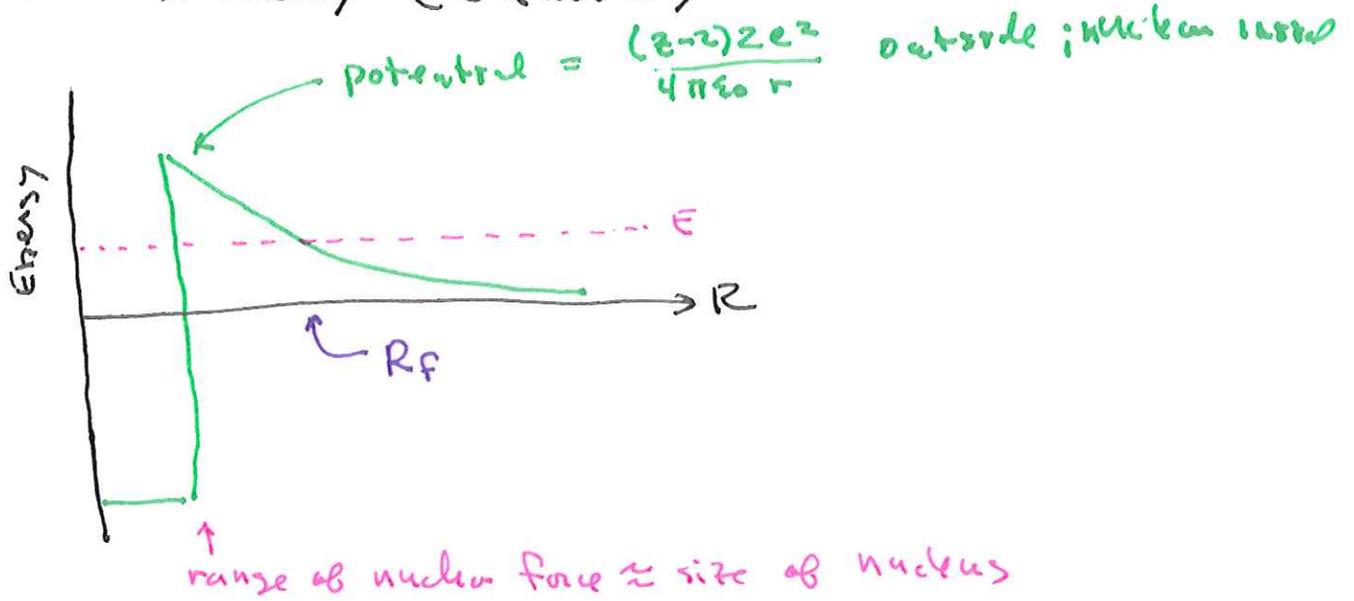
$n = 1, 3, 5$

$$\frac{1}{\pi} \int k dx + \frac{1}{4} \times [\text{\# linear}] = n$$

$$\int k dx = \pi \left(n - \frac{1}{4} [\text{\# linear}] \right)$$

typically there is 2 so $n - 1/2$. You'll often find this is books as $n + 1/2$. The difference is whether n starts at zero or one

Another common application of W.B.B is tunneling
eg in α decay (Gamow)



Classically an α inside the nucleus (or outside) cannot transit the disallowed region. Nevertheless we measure α s leaving nucleus (α decay) with an energy well below the barrier. Also we can cause nuclear reactions with α s that have too little energy to approach the nucleus. In the disallowed region ψ has expo decay — net reduction $e^{-\int_{R_f}^{\infty} K dx} = e^{-\gamma}$ as prob $\propto |\psi|^2 \rightarrow e^{-2\gamma}$. One can actually calculate the integral and compare to half-lives. The fit while not perfect explains a huge amount of the variation in half life.

Remark: There are lots of cases where can measure tunneling eg in e^- emission from cold cathode much as in 370 lab Thermionic Emission.